



DMN3018SSS

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = 25°C
30V	$21m\Omega @ V_{GS} = 10V$	7.3A
	$35m\Omega @ V_{GS} = 4.5V$	5.5A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

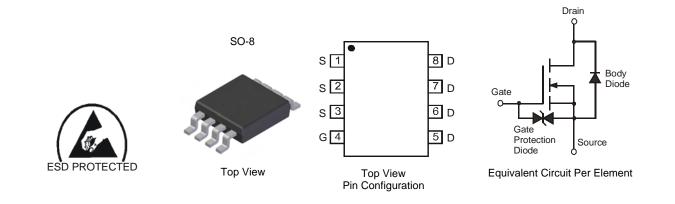
30V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- "Green" component and RoHS compliant (Notes 1 & 2)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)



Ordering Information (Note 3)

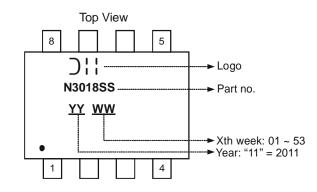
Part Number	Case	Packaging
DMN3018SSS-13	SO-8	2500/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units V V	
			V _{DSS}	30		
			V _{GSS}	±25		
	Steady State	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	7.3 5.7	A	
Continuous Drain Current (Note 5) V_{GS} = 10V	t<10s	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	9.7 7.8	А	
Continuous Drain Current (Note 5) V _{GS} = 4.5V	Steady State	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	5.5 4.3	А	
	t<10s	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	7.6 5.8	А	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	60	А	
Maximum Body Diode continuous Current			ls	2.5	А	

Thermal Characteristics @T_A = 25°C unless otherwise specified

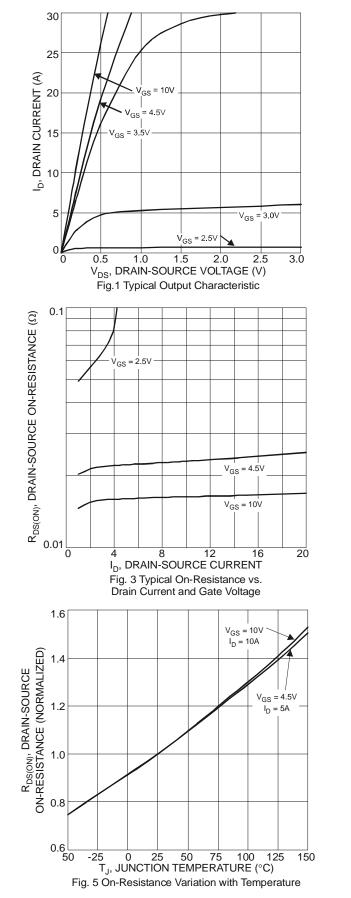
Characteristic		Symbol	Value	Units
Total Dawar Dissinction (Nata 4)	$T_A = 25^{\circ}C$	D	1.4	W
Total Power Dissipation (Note 4)	$T_A = 70^{\circ}C$	PD	0.9	
Thermal Resistance, Junction to Ambient (Note 4)	Steady state	P	90	°C/W
	t<10s	$R_{ extsf{ heta}JA}$	50	°C/W
Total Dawar Dissinction (Nata 5)	T _A = 25°C	D	1.7	W
Total Power Dissipation (Note 5)	$T_A = 70^{\circ}C$	PD	1.1	
Thermal Desistance Junction to Ambient (Note 5)	Steady state	P	75	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	42	°C/W
Thermal Resistance, Junction to Case (Note 5)		$R_{\theta JC}$	7.6	°C/W
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C

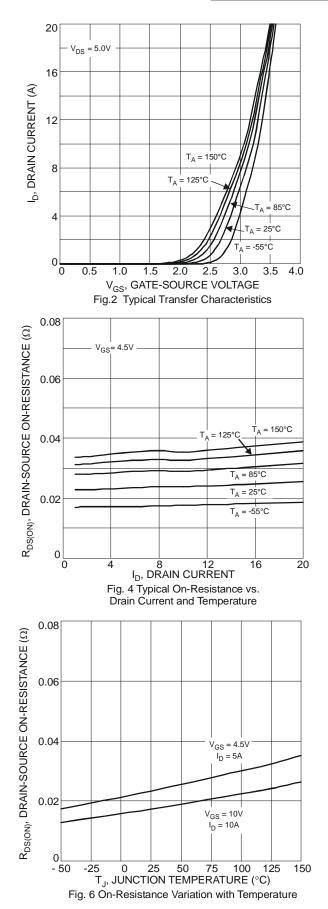
Electrical Characteristics T_A = 25°C unless otherwise specified

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	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)			i	i		
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	-	-	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	1	1.7	2.1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance		-	15	21	mΩ	$V_{GS} = 10V, I_D = 10A$
	R _{DS} (ON)	-	20	35		$V_{GS} = 4.5V, I_D = 8.5A$
Forward Transfer Admittance	Y _{fs}	-	8.3	-	S	$V_{DS} = 5V, I_D = 6.9A$
Diode Forward Voltage	V _{SD}	0.5	-	1.2	V	$V_{GS} = 0V, I_S = 1A$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss	-	697	-	pF	
Output Capacitance	C _{oss}	-	97	-	pF	−V _{DS} = 15V, V _{GS} = 0V, −f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	-	67	-	pF	
Gate resistance	Rg	-	1.47	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	6.0	-	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	-	13.2	-	nC	$V_{GS} = 10V, V_{DS} = 15V,$
Gate-Source Charge	Q _{gs}	-	2.2	-	nC	I _D = 9A
Gate-Drain Charge	Q _{gd}	-	1.8	-	nC	
Turn-On Delay Time	t _{D(on)}	-	4.3	-	ns	
Turn-On Rise Time	tr	-	4.4	-	ns	V _{DD} = 15V, V _{GS} = 10V,
Turn-Off Delay Time	t _{D(off)}	-	20.1	-	ns	$R_L = 15\Omega$, $I_D = 1A$, $R_G = 6\Omega$
Turn-Off Fall Time	t _f	-	4.1	-	ns	7
Reverse Recovery Time	T _{rr}	-	7.3	-	ns	
Reverse Recovery Charge	Qrr	-	7.9	-	nC	I _F = 9A, di/dt = 500A/µs

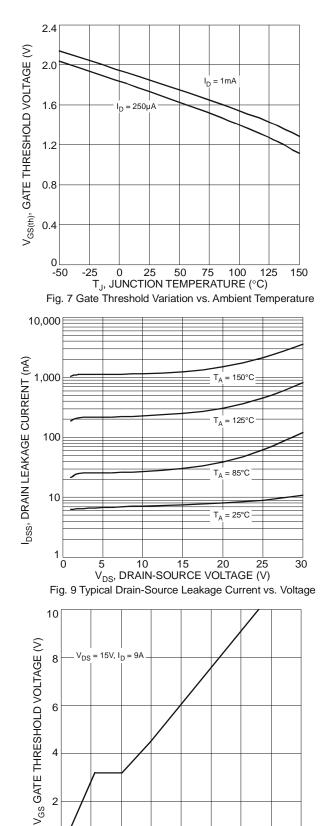
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:









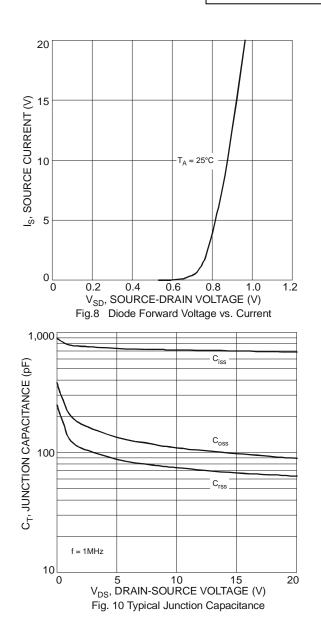


4 6 8 10 12 Q_g, TOTAL GATE CHARGE (nC)

Fig. 11 Gate Charge

14

16

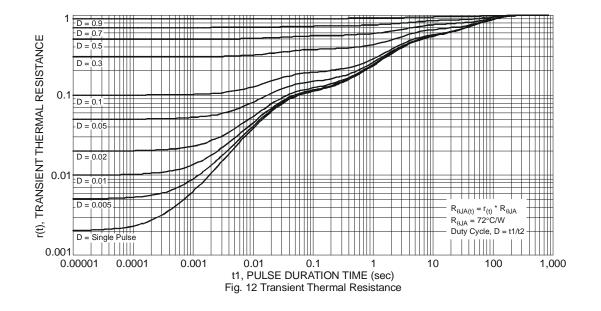


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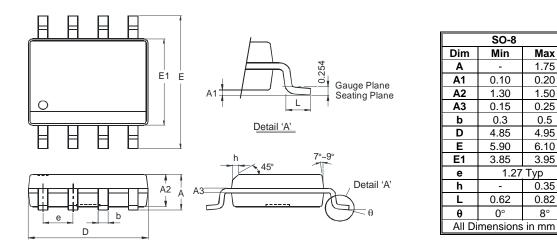
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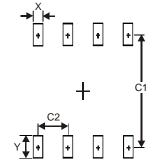




Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

SO-8

Min

0.10

1.30

0.15

0.3

4.85

5.90

3.85

0.62

0°

Max

1.75

0.20

1.50

0.25 0.5

4.95

6.10

3.95

0.35

0.82

8°

1.27 Typ

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